

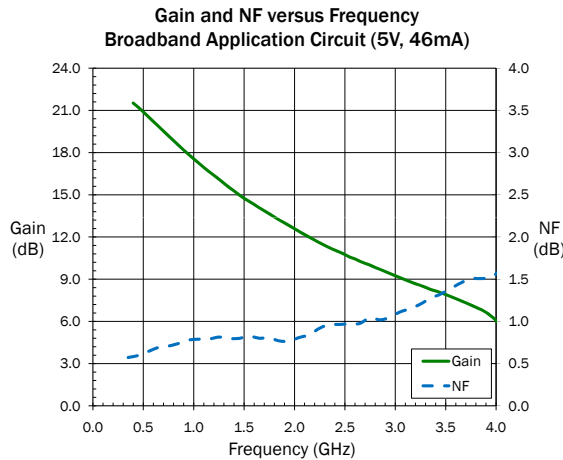


### Product Description

The SPF5043Z is a high performance pHEMT MMIC LNA designed for operation from 50MHz to 4000MHz. The on-chip active bias network provides stable current over temperature and process threshold voltage variations. The SPF5043Z offers ultra-low noise figure and high linearity performance in a gain block configuration. Its single-supply operation and integrated matching networks make implementation remarkably simple. The high maximum input power specification makes it ideal for high dynamic range receivers.

**Optimum Technology Matching® Applied**

- GaAs HBT
- GaAs MESFET
- InGaP HBT
- SiGe BiCMOS
- Si BiCMOS
- SiGe HBT
- GaAs pHEMT
- Si CMOS
- Si BJT
- GaN HEMT
- InP HBT
- RF MEMS
- LDMOS



### Features

- Ultra-Low Noise  
Figure=0.8dB at 900MHz
- Gain = 18.2dB at 900MHz
- High Linearity: OIP3 = 35dBm at 1900MHz
- P<sub>1dB</sub> = 22.7 dBm at 1900MHz
- Single-Supply Operation:  
5V at I<sub>DQ</sub> = 46mA
- Flexible Biasing Options: 3V to 5V, Adjustable Current
- Broadband Internal Matching

### Applications

- Cellular, PCS, W-CDMA, ISM, WiMAX Receivers
- Low Noise, High Linearity Gain Block Applications

| Parameter                             | Specification |      |      | Unit | Condition        |
|---------------------------------------|---------------|------|------|------|------------------|
|                                       | Min.          | Typ. | Max. |      |                  |
| Small Signal Power Gain               | 16.7          | 18.2 | 19.7 | dB   | 0.9GHz           |
|                                       | 11.4          | 12.9 | 14.4 | dB   | 1.96GHz          |
| Output Power at 1dB Compression       | 17.4          | 22.6 |      | dBm  | 0.9GHz           |
|                                       |               | 22.7 |      | dBm  | 1.9GHz           |
| Output Third Order Intercept Point    | 30.0          | 33.0 |      | dBm  | 0.9GHz           |
|                                       |               | 35.0 |      | dBm  | 1.9GHz           |
| Noise Figure                          |               | 0.80 | 1.0  | dB   | 0.9GHz           |
|                                       |               | 0.80 |      | dB   | 1.9GHz           |
| Input Return Loss                     | 13.0          | 16.0 |      | dB   | 0.9GHz           |
|                                       |               | 17.5 |      | dB   | 1.9GHz           |
| Output Return Loss                    | 14.5          | 17.5 |      | dB   | 0.9GHz           |
|                                       |               | 16.5 |      | dB   | 1.9GHz           |
| Reverse Isolation                     |               | 23.5 |      | dB   | 0.9GHz           |
|                                       |               | 19.0 |      | dB   | 1.9GHz           |
| Device Operating Voltage              |               | 5    | 5.25 | V    |                  |
| Device Operating Current (Quiescent)  | 28            | 46   | 54   | mA   |                  |
| Thermal Resistance (junction to lead) |               | 125  |      | °C/W | junction to lead |

Test Conditions: V<sub>D</sub>=5V, I<sub>DQ</sub>=46mA, OIP<sub>3</sub> Tone Spacing=1MHz, P<sub>OUT</sub> per tone=-5dBm, Z<sub>S</sub>=Z<sub>L</sub>=50Ω, 25°C, Broadband Application Circuit

## Absolute Maximum Ratings

| Parameter                             | Rating      | Unit |
|---------------------------------------|-------------|------|
| Max Device Current ( $I_D$ )          | 100         | mA   |
| Max Device Voltage ( $V_D$ )          | 5.5         | V    |
| Max RF Input Power                    | 25          | dBm  |
| Max Dissipated Power                  | 330         | mW   |
| Max Junction Temperature ( $T_J$ )    | 150         | °C   |
| Operating Temperature Range ( $T_L$ ) | -40 to + 85 | °C   |
| Max Storage Temperature               | -65 to +150 | °C   |
| ESD Rating - Human Body Model (HBM)   | Class 1A    |      |
| Moisture Sensitivity (MSL)            | MSL 1       |      |



**Caution!** ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RFMD Green: RoHS compliant per EU Directive 2002/95/EC, halogen free per IEC 61249-2-21, < 1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony in solder.

- Notes: 1. The maximum ratings must all be met simultaneously.  
 2.  $P_{DISS} = P_{DC} + PRF_{IN} - PRF_{OUT}$   
 3.  $T_J = T_L + P_{DISS} * R_{TH}$

Operation beyond any of these limits may cause permanent damage.

## Typical RF Performance - Broadband Application Circuit with $V_D=5V$ , $I_D=46mA$

| Parameter          | Unit | 0.1 GHz* | 0.4 GHz | 0.9 GHz | 1.5 GHz | 1.9 GHz | 2.2 GHz | 2.5 GHz | 3.5 GHz | 3.8 GHz |
|--------------------|------|----------|---------|---------|---------|---------|---------|---------|---------|---------|
| Small Signal Gain  | dB   | 23.5     | 21.6    | 18.2    | 14.8    | 13.1    | 11.9    | 10.8    | 8.0     | 7.0     |
| Noise Figure       | dB   | 0.65     | 0.61    | 0.74    | 0.82    | 0.78    | 0.84    | 0.96    | 1.34    | 1.49    |
| Output IP3         | dBm  | 30.5     | 31.0    | 33.0    | 34.5    | 35.0    | 35.5    | 36.5    | 38.5    | 37.5    |
| Output P1dB        | dBm  | na       | 22.5    | 22.6    | 22.7    | 22.7    | 23.0    | 22.8    | 23.1    | 22.8    |
| Input Return Loss  | dB   | -13.0    | -12.5   | -15.5   | -18.0   | -17.5   | -17.0   | -16.0   | -11.5   | -10.5   |
| Output Return Loss | dB   | -22.0    | -17.5   | -20.0   | -18.0   | -17.0   | -17.0   | -16.5   | -16.0   | -13.5   |
| Reverse Isolation  | dB   | -27.0    | -26.0   | -23.5   | -20.5   | -19.0   | -18.0   | -17.5   | -15.0   | -15.0   |

Test Conditions:  $V_D=5V$ ,  $I_{DQ}=46mA$ , OIP<sub>3</sub> Tone Spacing=1MHz, P<sub>OUT</sub> per tone=0dBm,  $T_L=25^{\circ}C$ ,  $Z_S=Z_L=50\Omega$ , \*Bias Tee Data @ 100MHz

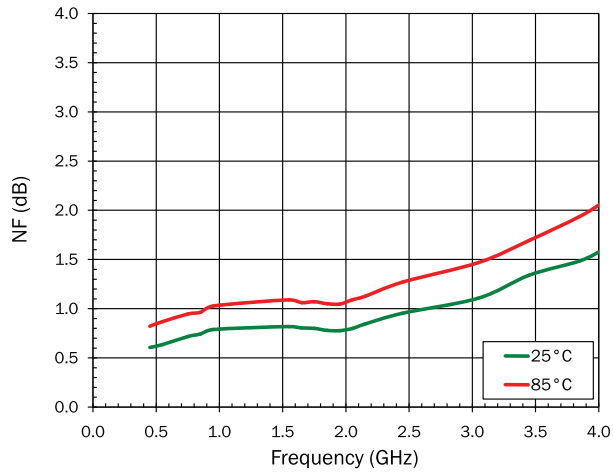
## Typical RF Performance - Broadband Application Circuit with $V_D=3V$ , $I_D=25mA$

| Parameter          | Unit | 0.1 GHz* | 0.4 GHz | 0.9 GHz | 1.5 GHz | 1.9 GHz | 2.2 GHz | 2.5 GHz | 3.5 GHz | 3.8 GHz |
|--------------------|------|----------|---------|---------|---------|---------|---------|---------|---------|---------|
| Small Signal Gain  | dB   | 22.6     | 20.9    | 17.7    | 14.4    | 12.7    | 11.5    | 10.5    | 7.6     | 6.7     |
| Noise Figure       | dB   | 0.60     | 0.61    | 0.73    | 0.82    | 0.78    | 0.85    | 0.93    | 1.28    | 1.48    |
| Output IP3         | dBm  | 26.5     | 27.0    | 28.5    | 30.0    | 30.5    | 30.5    | 32.0    | 33.5    | 33.0    |
| Output P1dB        | dBm  | na       | 19.3    | 19.5    | 19.9    | 20.0    | 20.3    | 20.2    | 20.3    | 19.7    |
| Input Return Loss  | dB   | -10.5    | -11.0   | -14.0   | -16.5   | -16.5   | -16.0   | -14.5   | -10.5   | -9.5    |
| Output Return Loss | dB   | -21.0    | -21.5   | -28.5   | -24.5   | -22.5   | -22.5   | -22.5   | -20.0   | -15.5   |
| Reverse Isolation  | dB   | -26.0    | -25.5   | -22.5   | -20.0   | -18.0   | -17.5   | -16.5   | -14.5   | -14.0   |

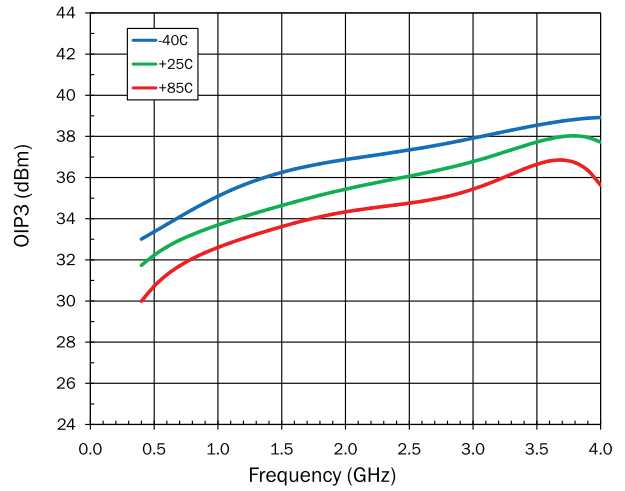
Test Conditions:  $V_D=3V$ ,  $I_{DQ}=25mA$ , OIP<sub>3</sub> Tone Spacing=1MHz, P<sub>OUT</sub> per tone=0dBm,  $T_L=25^{\circ}C$ ,  $Z_S=Z_L=50\Omega$ , \*Bias Tee Data @ 100MHz

Typical RF Performance - Broadband Application Circuit with  $V_D=5V$ ,  $I_D=46mA$

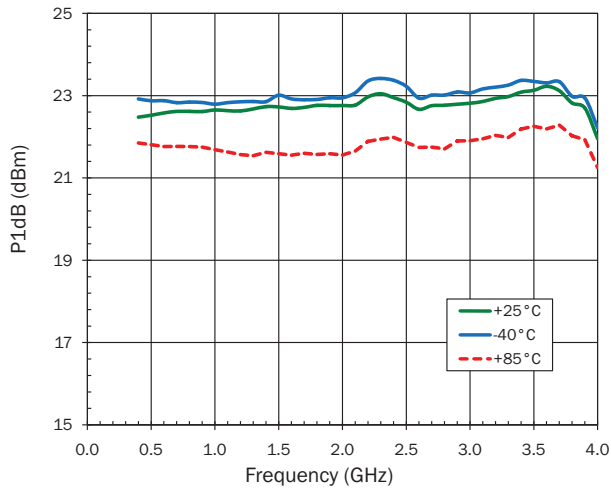
NF versus Frequency



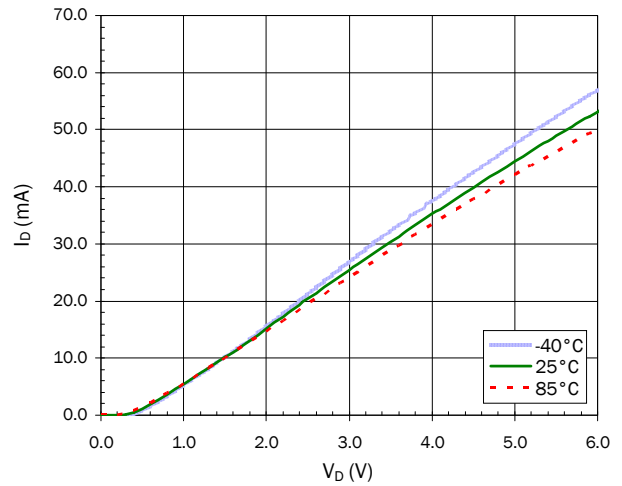
OIP3 vs. Frequency (-5dBm/tone, 1MHz spacing)



P1dB versus Frequency

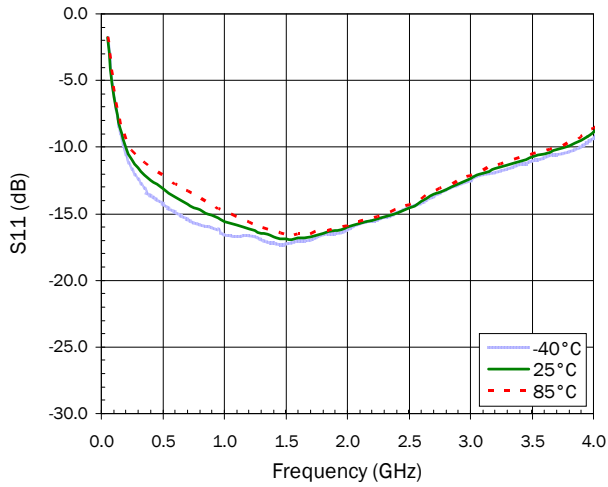


Device Current versus Voltage

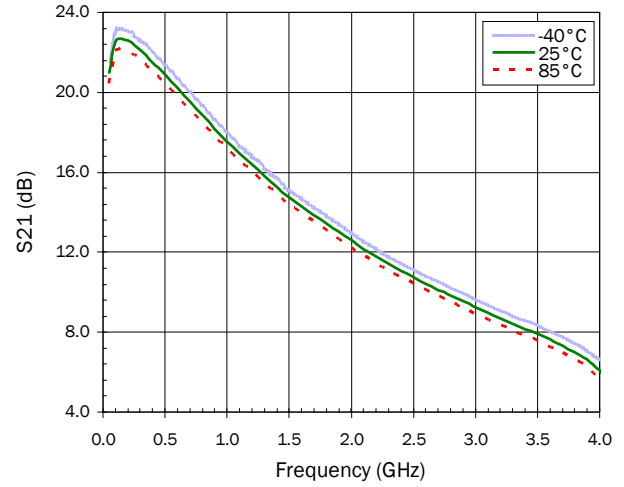


Typical RF Performance - Broadband Application Circuit with  $V_D=5V$ ,  $I_D=46mA$

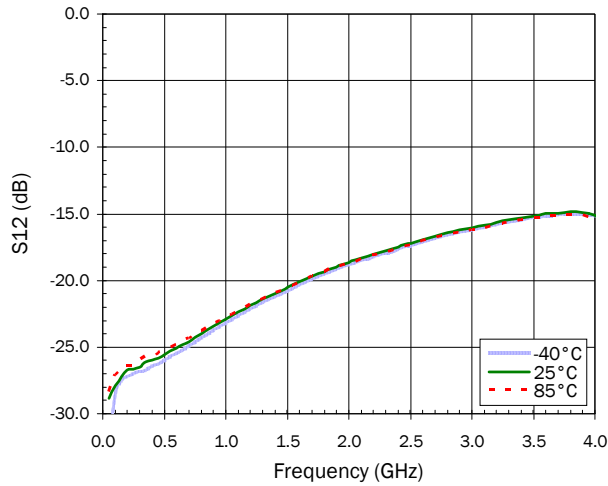
**S11 versus Frequency**



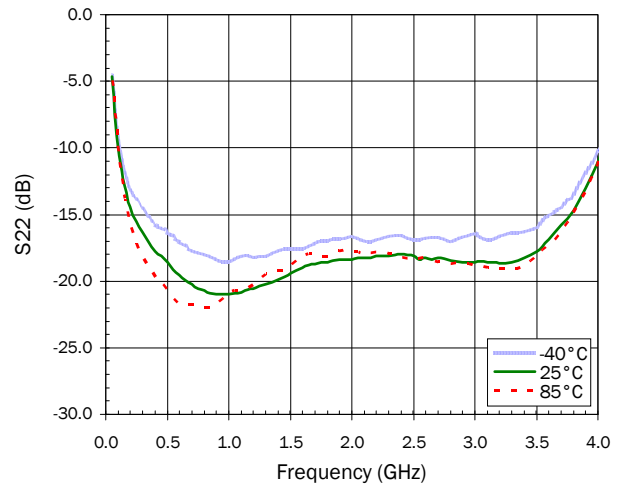
**S21 versus Frequency**



**S12 versus Frequency**

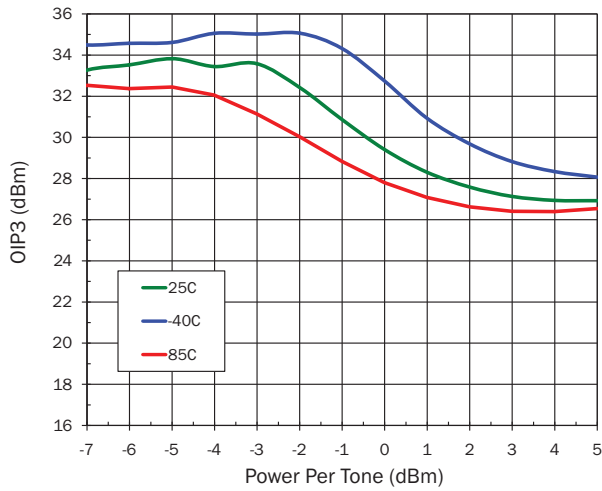


**S22 versus Frequency**

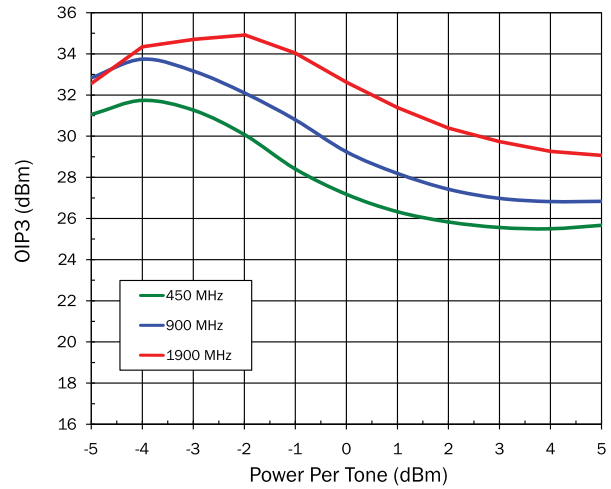


Typical RF Performance - Broadband Application Circuit with  $V_D=5V$ ,  $I_D=46mA$

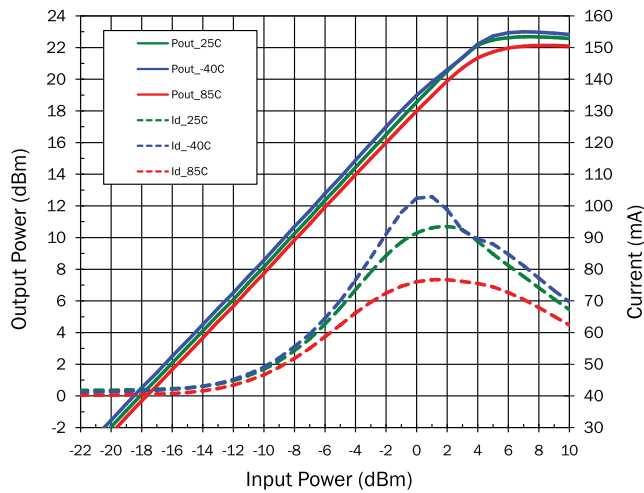
OIP3 versus Power Out (Vd = 5V, 900MHz)



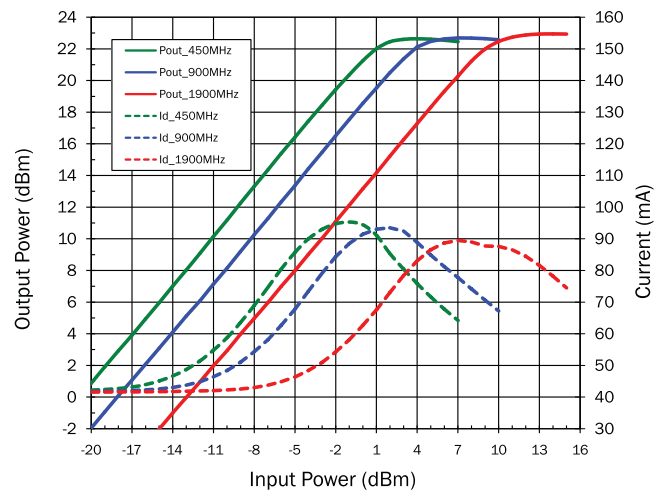
OIP3 versus Power Out (Vd = 5V, 25C)



Output Power versus Input Power (Vd=5V, 900 MHz)

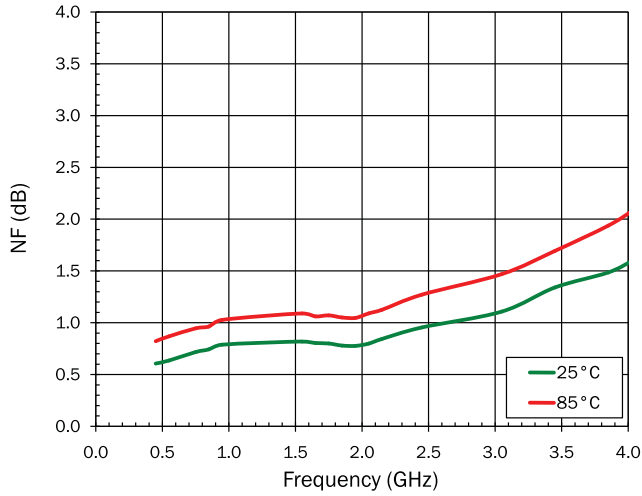


Output Power versus Input Power (Vd=5V)

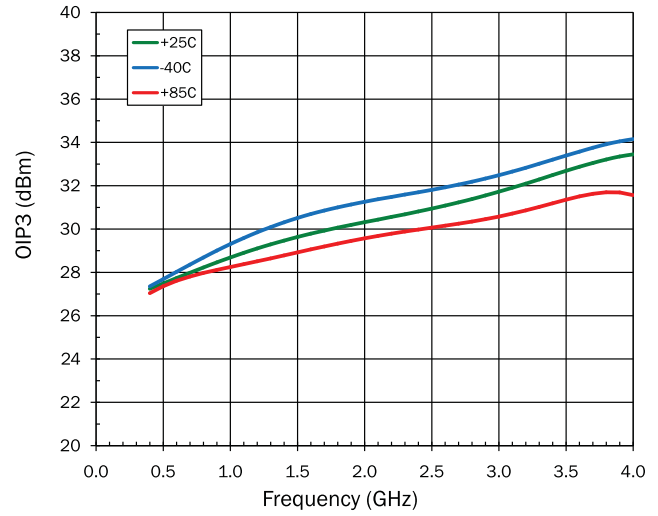


Typical RF Performance - Broadband Application Circuit with  $V_D=3V$ ,  $I_D=25mA$

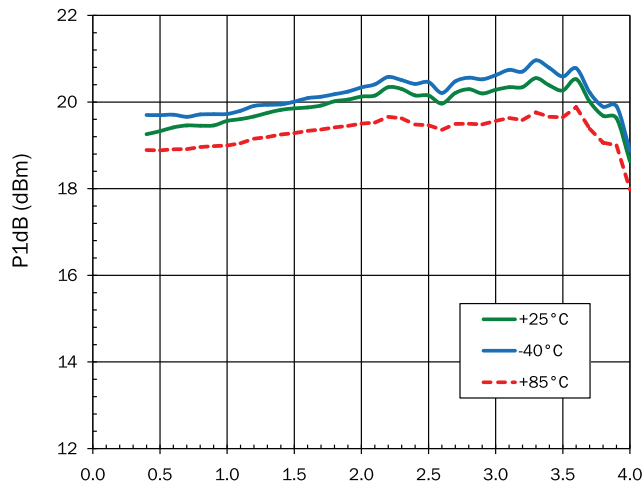
NF versus Frequency



OIP3 vs. Frequency (-5dBm/tone, 1MHz spacing)

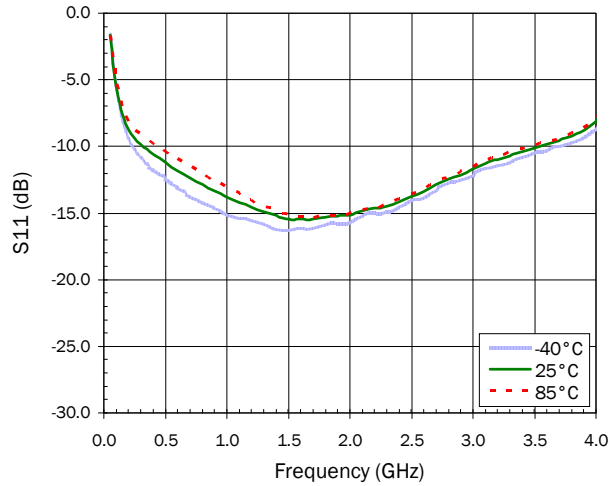


P1dB versus Frequency

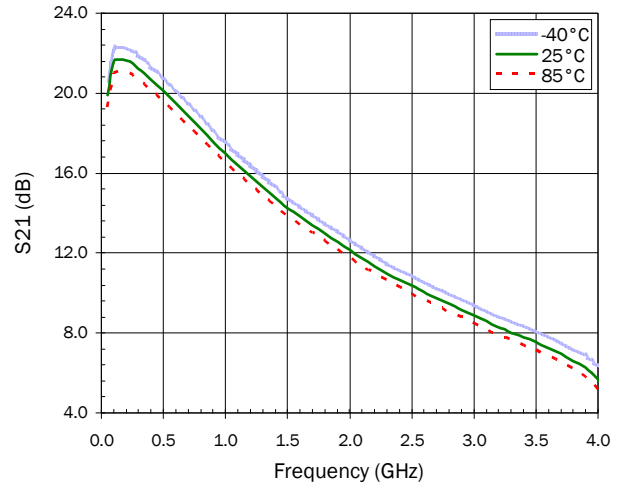


Typical RF Performance - Broadband Application Circuit with  $V_D=3V$ ,  $I_D=25mA$

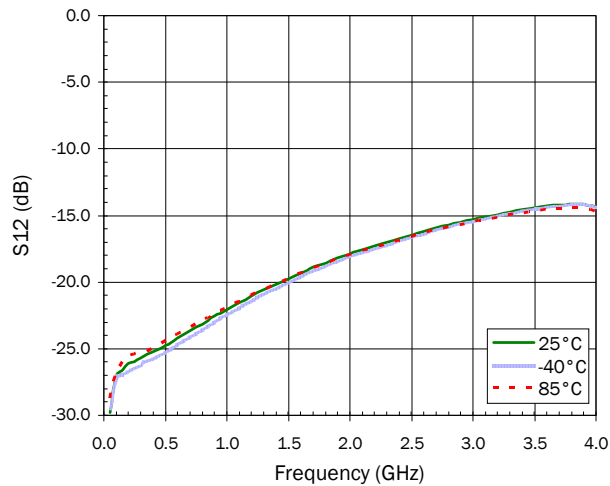
**S11 versus Frequency**



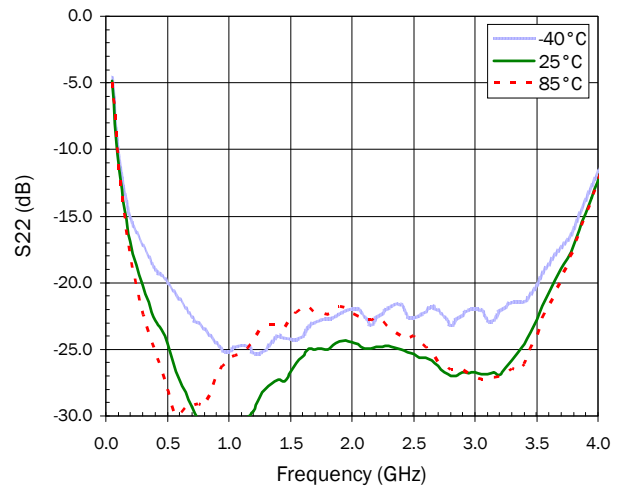
**S21 versus Frequency**



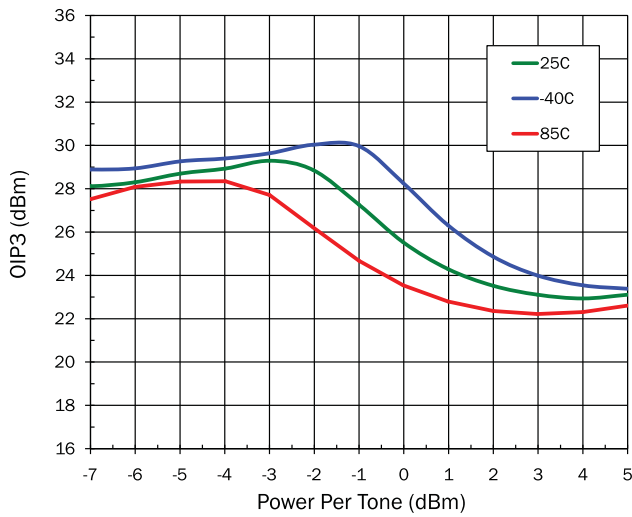
**S12 versus Frequency**



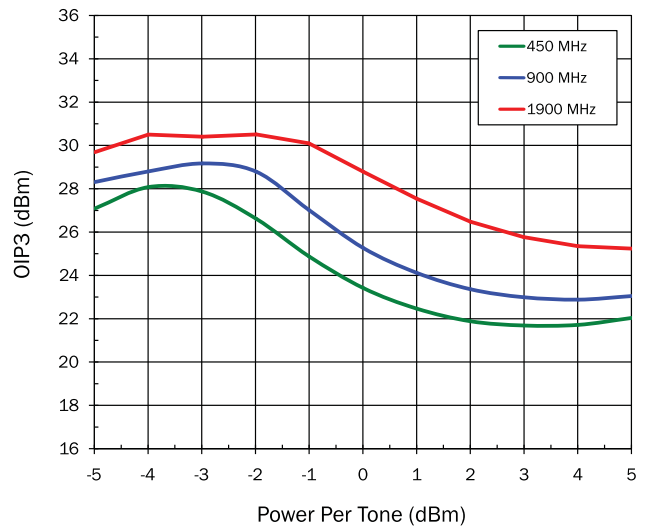
**S22 versus Frequency**



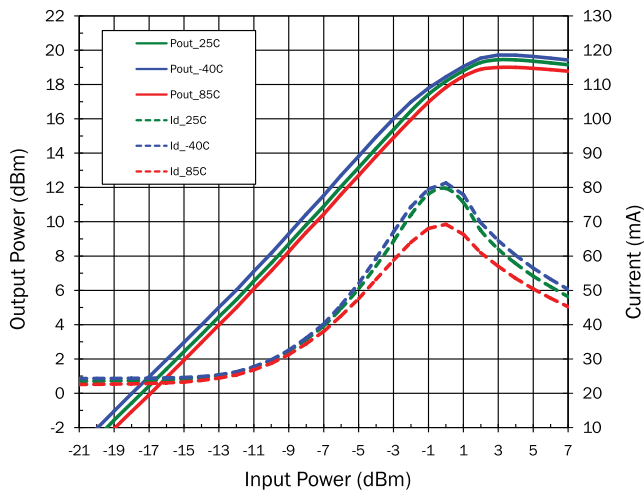
Typical RF Performance - Broadband Application Circuit with  $V_D=3V$ ,  $I_D=25mA$   
 OIP3 versus Power Out ( $V_d = 3V$ , 900MHz)



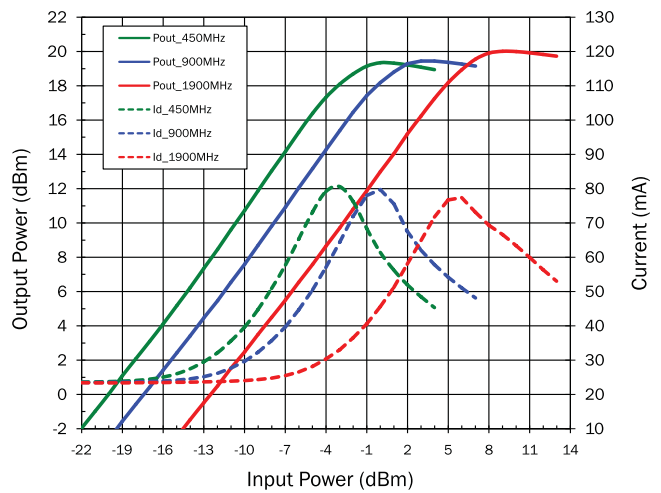
OIP3 versus Power Out ( $V_d = 3V$ , 25C)



Output Power versus Input Power ( $V_d=3V$ , 900 MHz)



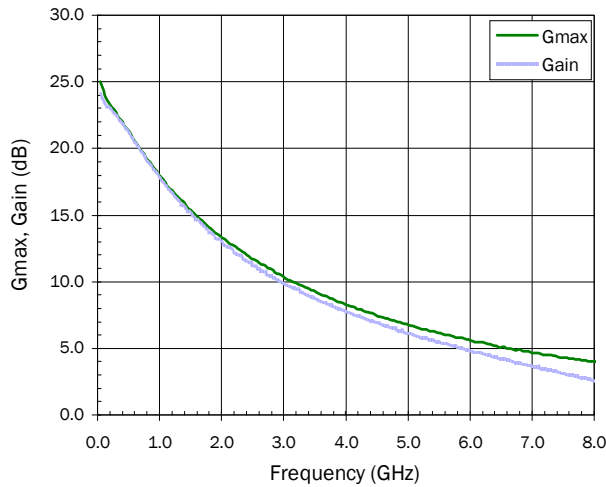
Output Power versus Input Power ( $V_d=3V$ )



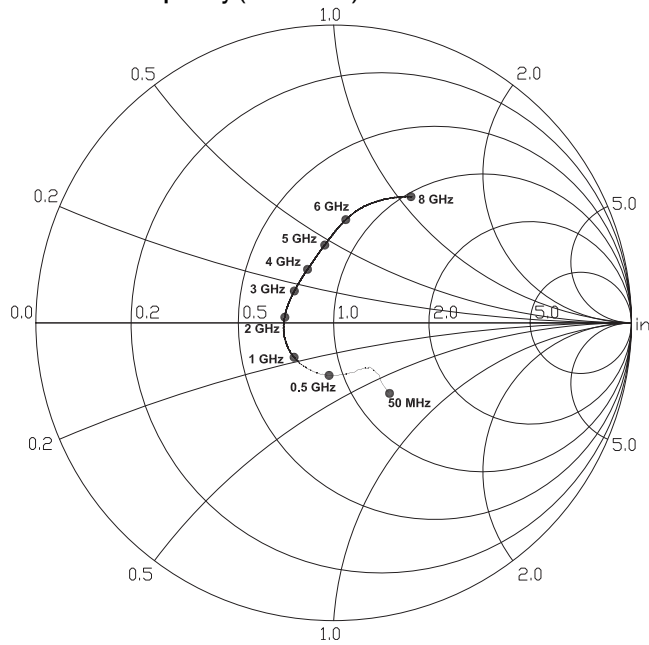


De-embedded Device S-parameters (Bias Tee Data)

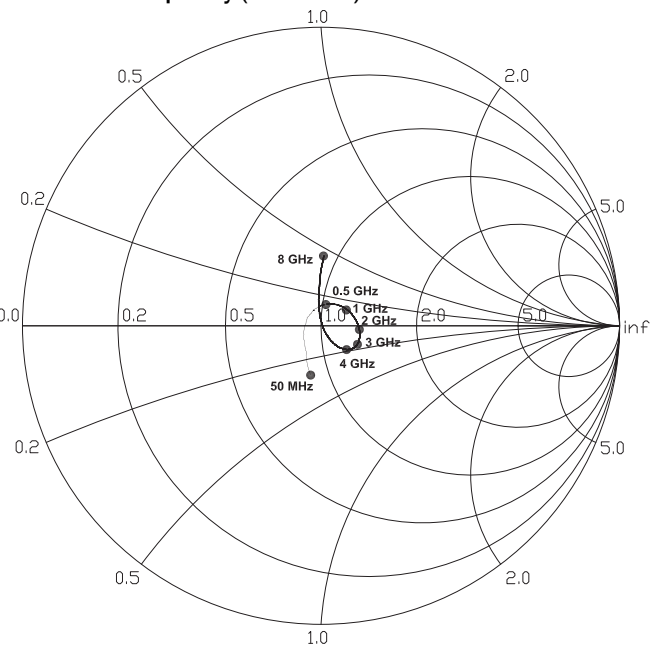
Gmax versus Frequency (5V,46mA)



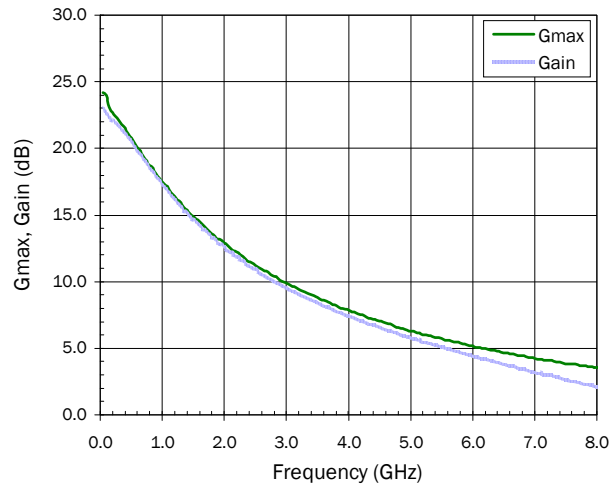
S11 versus Frequency (5V 46mA)



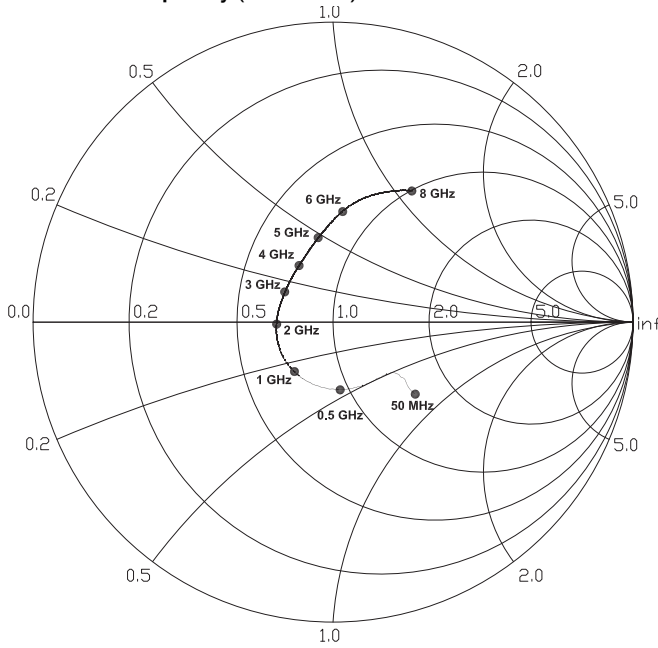
S22 versus Frequency (5V 46mA)



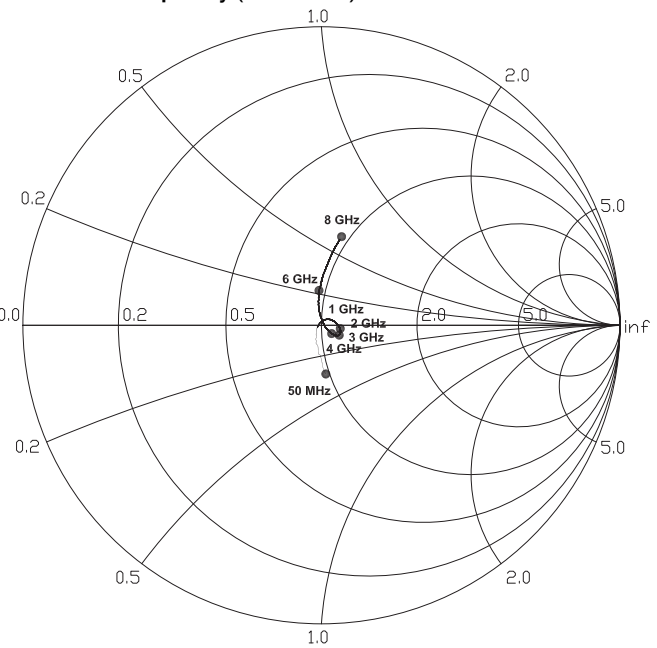
**Gmax versus Frequency (3V, 25mA)**



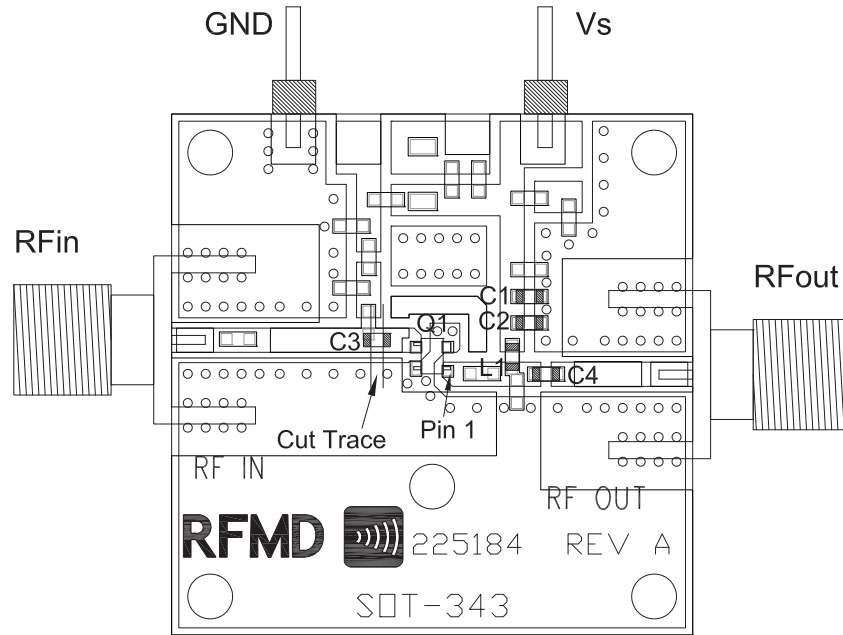
**S11 versus Frequency (3V 25mA)**



**S22 versus Frequency (3V 25mA)**



**Evaluation Board Layout**

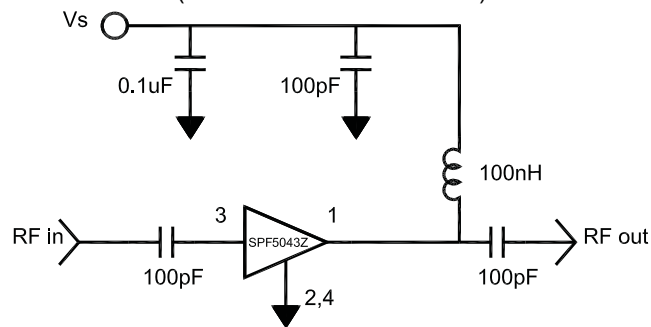


**Bill of Materials (SPF5043Z, 400MHz to 3000MHz)**

|    |                            |
|----|----------------------------|
| C1 | TAJB104KLR, Rohm, 0.1uF    |
| C2 | MCH185A101JK, Rohm, 100pF  |
| C3 | MCH185A101JK, Rohm, 100pF  |
| C4 | MCH185A101JK, Rohm, 100pF  |
| L1 | LL1608-FSR10J, Toko, 100nH |

**Application Schematic**

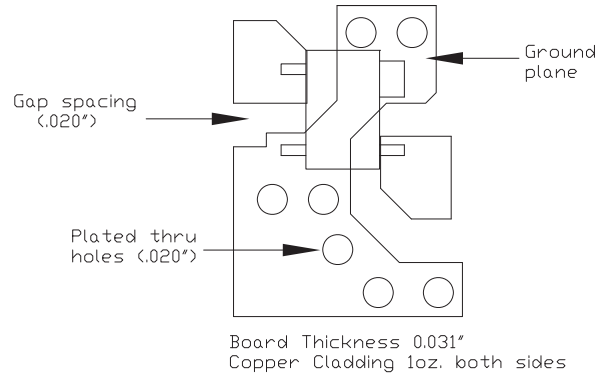
(400MHz to 3000MHz)



## Pin Names and Description

| Pin | Function    | Description   |
|-----|-------------|---|
| 1   | RF OUT/BIAS | RF Output Pin. This Pin is DC Coupled and Matched to 50Ω. An external DC block is required. |
| 2   | GND         | Connection to ground.   |
| 3   | RF IN       | RF Input Pin. This Pin is DC Coupled and Matched to 50Ω. An external DC block is required.  |
| 4   | GND         | Connection to ground.   |

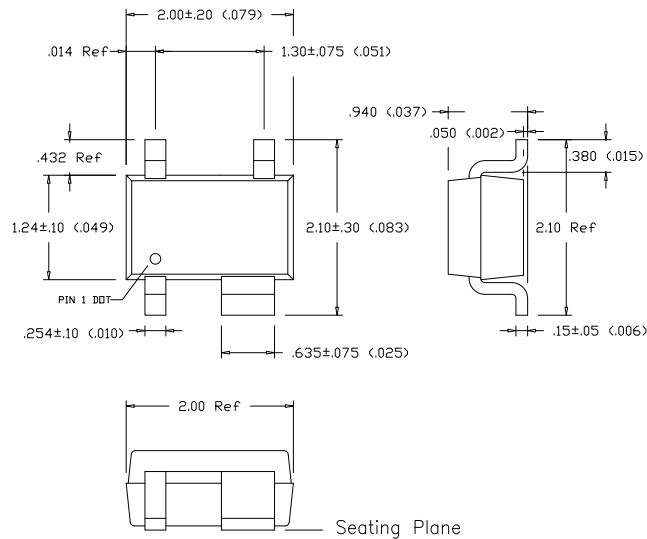
## Suggested Pad Layout



## Package Drawing

Dimensions in inches (millimeters)

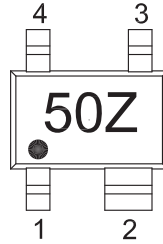
Refer to drawing posted at [www.rfmd.com](http://www.rfmd.com) for tolerances.



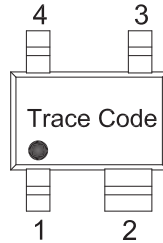
### Notes:

1. Lead Base Metal - Copper  $\square$ lin 194
2. Lead Finish - 100% Matte Sn - .010 (.0004) min thk

**Legacy Part Identification Marking - No Trace Code**



**Primary Part Identification Marking - Trace Code Only**



**Ordering Information**

| Ordering Code | Description                                    |
|---------------|--|
| SPF5043Z      | 7" Reel with 3000 pieces                       |
| SPF5043ZSQ    | Sample bag with 25 pieces                      |
| SPF5043ZSR    | 7" Reel with 100 pieces                        |
| SPF5043ZPCK1  | 400MHz to 3000MHz PCBA with 5-piece sample bag |